



# High-Efficiency CRM/CCM Multi-Mode Operation Power Factor Correction Controller

## General Description

AT6101L is a active power factor corrected controller to drive PFC boost stages base on ATK patented Pseudo Digital Control(PDC) method.

In PDC loop ,AT6101L classically operates in Critical conduction Mode(CRM) when the inductor current below a programmable value.

When the current is exceed this preset level ,the AT6101L natural change to Continuous conduction Mode(CCM).The loop stability and response is controlled by

PDC Loop. AT6101L features a robust suite of protection features to properly handel an array of power supply operating and fault condition.

The devices is available in SOP-14L package and require few external devices for operation.

## Features

- Pseudo Digital Control Loop without Analog multiplier(patent protected)
- Quick Transient Response
- Intelligent AC Power Sag Protection
- Multi-Mode CRM/CCM operation
- Programmable Soft Start
- Programmable CCM Operation Frequency 18kHz~130kHz
- Sourcing 1A/Sinking 1A High Drive Cability Driver
- Brown In/Out protection
- Bias-Supply UVLO ,Over-Voltage Protection ,Open-Loop Detection ,
- SOP-14L Package

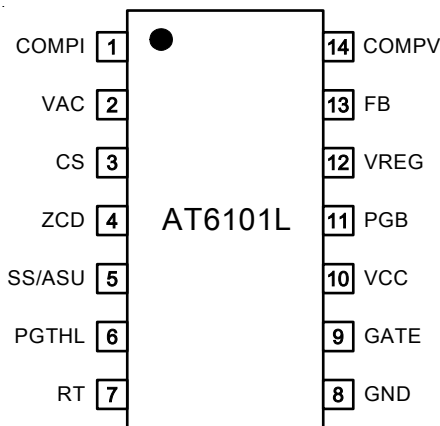
## Applications

- High Efficiency Server and Desktop Power Supplies
- Telecom Rectifiers
- High Power Adaptor
- Off Line Appliances Requiring Power Factor Correction

## Function Marking Information

Top Marking	Switching Frequency	Vout level Boost
AT6101L	ADJ	Low Line Active

## Pin Configuration



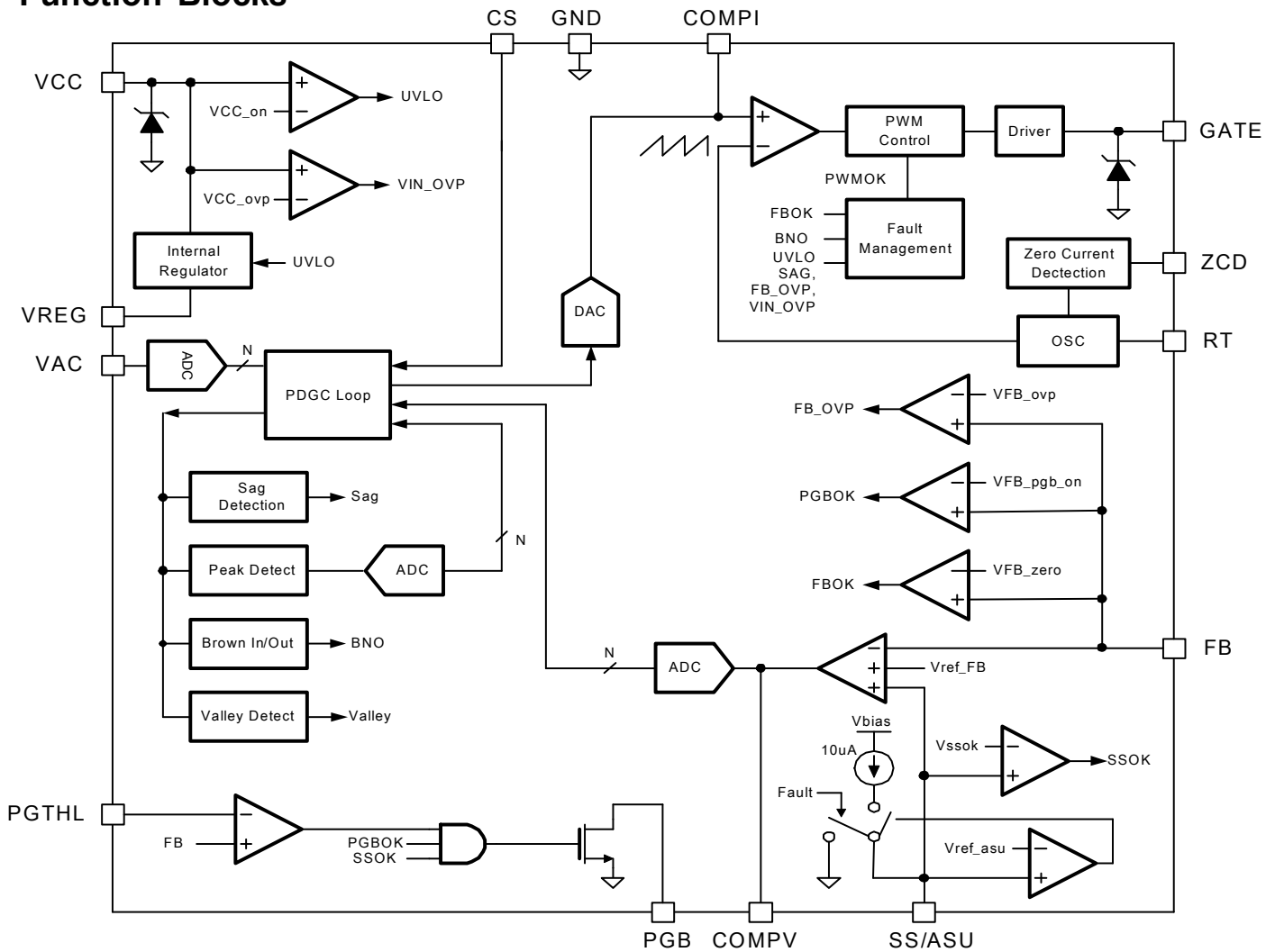
## Ordering and Marking Information

Order Number	Package	Top Marking
AT6101LSPC	SOP-14L	AT6101L

Note: Aplustek products are compatible with the current IPC/JEDEC J-STD-020 requirement. They are halogen-free, RoHS compliant and 100% matte tin (Sn) plating that are suitable for use in SnPb or Pb-free soldering processes.



## Function Blocks



## Function Pin Description

No.	Pin Name	Pin Function
1	COMPI	Current error amplifier output.
2	VAC	AC line sense input pin.
3	CS	PFC current sense.
4	ZCD	Zero current detect input Pin.
5	SS/ASU	Soft Start time setting input pin. Connect to 0.1uF output capacitor.
6	PGTHL	An I/O pin. Setting for Power Good threshold to determine PGB to be pull high level.
7	RT	CCM switching Frequency input pin.
8	GND	Ground.
9	Gate	Gate Driver output Pin.
10	VCC	Positive Supply for AT6101Z.
11	PGB	Power Good comparetor output pin.
12	VREG	Reference Voltage output pin.
13	FB	Voltage error amplifier input.
14	COMPV	Voltage error amplifier output.



## Absolute Maximum Ratings

(Note1)

Supply Input Voltage, $V_{cc}$	-----	-0.3V to +27V
PGB to GND DC	-----	-0.3V to +27V
CS to GND DC	-----	-6V to +0.3V
Gate to GND DC	-----	-0.3V to clamping voltage+6V(~21V)
COMPI,VAC,ZCD,SS/ASU,PGTHL,RT,VREG,FB,COMPV to GND DC	-----	-0.3V to +7V
Storage Temperature Range	-----	-65°C to +150°C
Junction Temperature	-----	-40°C to +150°C
Lead Temperature Range(Soldering 10sec)	-----	260°C
ESD Rating (Note2)		
HBM(Human Body Mode)	-----	-2KV
MM(Mechine Mode)	-----	-200V

## Thermal Characteristics

Package Thermal Resistance (Note3)

SOP-14L $\theta_{JA}$	-----	100°C/W
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Power Dissipation, PD @ TA = 25°C

SOP14-14L	-----	1W
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## Electrical Characteristics

(  $V_{cc} = 12V$ ,  $T_A = +25°C$  unless otherwise specified.)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
<b>VCC Supply Input Section</b>						
VCC operation range			10	--	21	V
VCC UVLO threshold	$V_{CC,on}$	VCC Rising	--	10	--	V
	$V_{CC,off}$	VCC Falling	--	8	--	V
Over Voltage Protection Voltage	$V_{CC,ovp}$			24		V
Inter Zener Clamp	$V_{CC,clamp}$	$I_{VCC}=10mA$ , $CL=0$		27		V
Startup current	$I_{CC,start}$			35	70	uA
Normal operation current	$I_{CC,op}$	$CL=2nF$	--	2.5	3.5	mA
<b>VAC Section</b>						
Brown In Threshold	VAC_brown_in		--	1	--	V
Brown In Debounce Time	Tdeb_brown_in			200		uS
Brown Out Threshold	VAC_brown_out		--	0.94	--	V
Brown Out Debounce Time	Tdeb_brown_out			440		mS
Pull low Impedance	ZVAC			500		kohm
High Line Threshold	VAC_hline	Sweep VAC from low to high		2.35		V
Low Line Threshold	VAC_lline	Sweep VAC from high to low		2.1		V
Low Threshold for Valley Detect	VAC_valley_l			0.35		V
High Threshold for Valley Detect	VAC_valley_h			0.72		V
SAG Debounce Time	Tdeb_sag			5		mS
Product of VAC Peak and Internal VAC Peak				5.4		V*V



Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
<b>CS Section</b>						
Delay to Output				250		nS
Threshold to off PWM at low Line	VCS_max_lline		--	-1.56	--	V
Threshold to off PWM at high Line	VCS_max_hline		--	-0.94	--	V
Input Impedance	ZCS		20			kohm
Max Fain of CS over Internal VAC				0.2		V/V
<b>ZCD Section</b>						
Negative Clamp Voltage	VZCD_clamp_l		--	-0.6	--	V
Positive Clamp Voltage	VZCD_clamp_h			6.1		V
Falling Threshold for Zero Current Detection	VZCD_zero_fall	Sweep ZCD from high to low		0.4		V
Rising Threshold for Zero Current Detection	VZCD_zero_rise	Sweep ZCD from low to high		0.5		V
Threshold to Keep low to off CRM mode	VZCD_crm_off	For CCM fix Fsw operation , force ZCD< VZCD_crm_off		0.4		V
Threshold to Keep high to off PWM mode	VZCD_pwm_off	For SD AT6101 Gate , force ZCD< VZCD_pwm_off		0.5		V
<b>SS/ASU Section</b>						
Voltage lower than VCC in Power On for ASU mode				2		V
Charging Current in SS mode	ISS			10		uA
Soft Start Time in ASU mode	t_ss			175		mS
<b>PGTHL Section</b>						
FB voltage to pull PGB High at High FB mode	VFB_pgb_off_hfb	PGTHL=2V	1.98		2.02	V
FB voltage to pull PGB High at Low FB mode	VFB_pgb_off_lfb	PGTHL=2V	1.8		1.89	V
<b>RT Section</b>						
Nominal Frequency	fosc	connect 100kohm to GND		65		kHz
Resister Range			40		400	kohm
Frequency Variation vs.VCC					2	%
Frequency Variation vs. Temperature					2	%

**Note 1.** Exceeding these limits may impair the life of the device. Exposure to absolute maximum rating conditions for long periods may affect device reliability.

**Note 2.**  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. The exposed pad of the package is soldered directly on the PCB.



Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
<b>COMPI Section</b>						
Transconductance	gm_compi			72		uohm
Input Offset Voltage	vos_compi		-1		1	mV
Max Sink Current	Isink_max_compi		-	-36	-	uA
Max Source Current	Isource_max_compi			36		uA
Clamp High Voltage	VCOMPI_clamp_h			4.3		V
Clamp Low Voltage	VCOMPI_clamp_l			0.52		V
Threshold for Zero Duty	VCOMPI_zero			0.77		V
<b>COMPV Section</b>						
Transconductance	gm_compv			72		uohm
Input difference with GM Boost	Vdiff_gn_boost			-100		mV
Transconductance with GM Boost	gm_compvl_boost			163		uohm
Max Sink Current	Isink_max_compv			36		uA
Max Source Current	Isource_max_compv			36		uA
Clamp High Voltage	VCOMPV_clamp_h			4.3		V
Clamp Low Voltage	VCOMPV_clamp_l			0.72		V
Threshold for Zero Duty	VCOMPV_bs			0.8		V
Threshold for Low Vout Mode	VCOMPV_lfb	Sweep COMPV from High to Low		2.54		V
Threshold for High Vout Mode	VCOMPV_hfb	Sweep COMPV from Low to High		2.84		V
<b>FB Section</b>						
Reference Voltage at High Feedback Mode	Vref_FB_hfb			2.515		V
Reference Voltage at Low Feedback Mode	Vref_FB_lfb			2.35		V
Debounce of Vout Boost Mode	Tdeb_lfb			1		S
Threshold for FB OVP	VFB_ovp	Sweep FB from Low to High		2.75		V
Hysteresis of FB OVP Threshold				200		mV
Threshold for PGB Pull Low	VFB_pgb_on			2.2		V
Threshold to off PWM	VFB_pwm_off			0.4		V
<b>VREG Section</b>						
Output Voltage	Vreg			6		V
Line Regulation					5	mV
Load Regulation		0mA<l<3mA			20	mV
Max Output Current			10			mA
<b>PGB Section</b>						
Output Voltage Low	Vpgb_ol	Ib=1mA Sinking			0.5	V



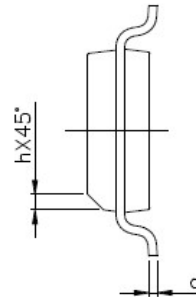
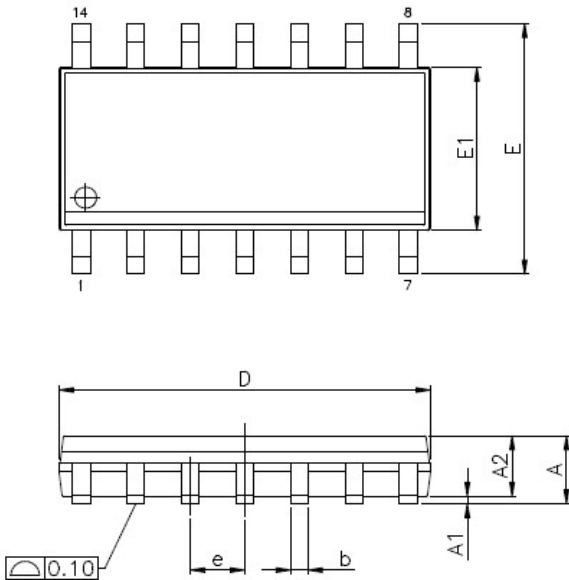
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
<b>Gate Section</b>						
Maximum Duty Cycle	Dmax			98		%
Output Voltage Low	V <sub>ol</sub>	VCC=12V, I <sub>o</sub> =20mA Sinking			0.15	V
Output Voltage High	V <sub>oh</sub>	VCC=12V, I <sub>o</sub> =20mA Sinking	10			V
Rising Time	t <sub>r</sub>	CL=2nF, V <sub>GATE</sub> from 2V to 6V		30		nS
Falling Time	t <sub>f</sub>	CL=2nF, V <sub>GATE</sub> from 6V to 2V		10		nS
Gate Clamping Voltage	V <sub>gate_clamp</sub>	VCC=21V	12	15	18	V
<b>TSD Section</b>						
Internal Thermal Protection	TSD_int			150		Degr- ee
Hysteresis of Thermal Protection	TSD_int_hys			20		

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## Package Information

SOP-14L



SYMBOLS	MIN.	MAX.
A	—	1.75
A1	0.10	0.25
A2	1.25	—
b	0.31	0.51
c	0.10	0.25
D	8.65 BSC	
E	6.00 BSC	
E1	3.90 BSC	
e	1.27 BSC	
L	0.40	1.27
h	0.25	0.50
$\theta^\circ$	0	8

UNIT : mm

### Note

#### 1. Package Outline Unit Description:

BSC: Basic. Represents theoretical exact dimension .

MAX: Maximum dimension specified.

MIN: Minimum dimension specified.

REF: Represents dimension for reference use only. The value is not the device specification.

TYP: Represents as a typical value. The value is not the device specification.

#### 2. All linear dimensions are in Millimeters.



